COMPLIANT

HALOGEN

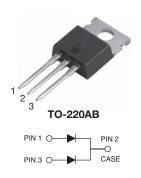
FREE



Vishay General Semiconductor

Dual High Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.41 \text{ V}$ at $I_F = 5.0 \text{ A}$



PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 20 A						
V_{RRM}	100 V						
I _{FSM}	250 A						
V _F at I _F = 20 A (T _J = 125 °C)	0.61 V						
T _J max.	175 °C						
Package	TO-220AB						
Circuit configuration	Common cathode						

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C maximum, 10 s per JESD 22-B106
- AEC-Q101 qualified available:
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	VX40M100C	UNIT				
Maximum repetitive peak reverse voltage		V_{RRM}	100	V				
Maximum average forward rectified current (fig. 1)	per device	,	40	Α				
	per diode	I _{F(AV)}	20					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	250	А				
Operating junction temperature range		T _J ⁽¹⁾	-40 to +175	°C				
Storage temperature range		T _{STG}	-40 to +175]				

Note

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: dP_D/dT_J < 1/R_{8,IA}



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ELECTRICAL CHARACTERISTICS (T _J = 25 °C unless otherwise noted)								
PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP.	MAX.	UNIT		
	I _F = 5 A		V _F ⁽¹⁾	0.50	-	V		
	I _F = 10 A	T _J = 25 °C		0.58	-			
Instantaneous forward voltage per diode	I _F = 20 A			0.71	0.76			
	I _F = 5 A			0.41	-			
	I _F = 10 A	T _J = 125 °C		0.51	-			
	I _F = 20 A]		0.61	0.67			
Reverse current at rated V _R per diode	V _R = 70 V	T _J = 25 °C	I _B ⁽²⁾	0.003	-	· mA		
	v _R = 70 v	T _J = 125 °C		3	-			
	V _R = 100 V	T _J = 25 °C	IR (=/	-	0.22			
	v _R = 100 v	T _J = 125 °C		6	20			
Typical junction capacitance	4.0 V,	4.0 V, 1 MHz		2000	-	pF		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 5 \text{ ms}$

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VX40M100C	UNIT			
Typical thermal resistance per device	R _{0JC} (1)	1	°C/W			

Note

(1) Thermal resistance junction-to-case to follow JEDEC® 51-14 transient dual interface test method (TDIM)

ORDERING INFORMATION (Example)							
PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY N							
VX40M100C-M3/P	2.03	Р	50/tube	Tube			
VX40M100CHM3/P (1)	2.03	Р	50/tube	Tube			

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

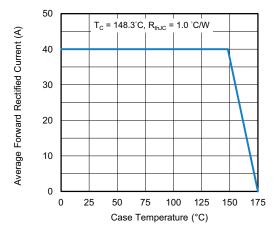


Fig. 1 - Maximum Forward Current Derating Curve

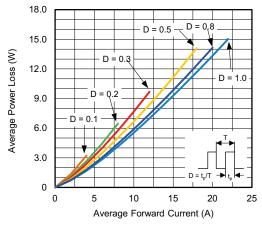


Fig. 2 - Average Power Loss Characteristics

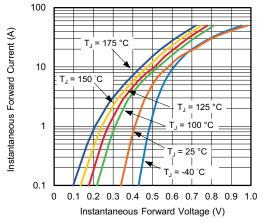


Fig. 3 - Typical Instantaneous Forward Characteristics

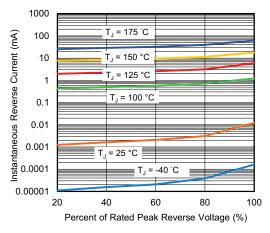


Fig. 4 - Typical Reverse Leakage Characteristics

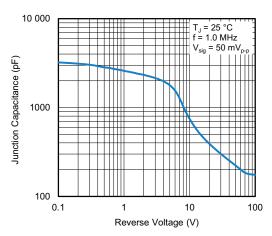


Fig. 5 - Typical Junction Capacitance

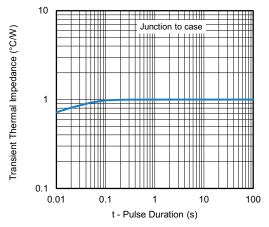
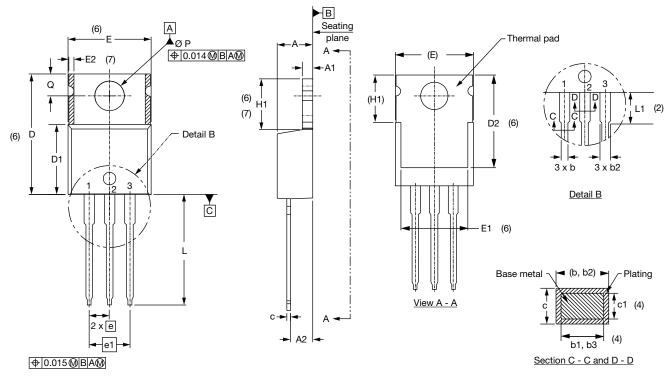


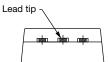
Fig. 6 - Typical Transient Thermal Impedance



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DIMENSIONS in millimeters (inches) **TO-220AB**





Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	NOTES	NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6	
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6	
A2	2.56	2.92	0.101	0.115			E1	6.86	8.89	0.270	0.350	6	
b	0.69	1.01	0.027	0.040			E2	-	0.76	1	0.030	7	
b1	0.38	0.97	0.015	0.038	4		е	2.41	2.67	0.095	0.105		
b2	1.20	1.73	0.047	0.068			e1	4.88	5.28	0.192	0.208		
b3	1.14	1.73	0.045	0.068	4		H1	5.84	6.86	0.230	0.270	6, 7	
С	0.36	0.61	0.014	0.024			L	13.52	14.02	0.532	0.552		
c1	0.36	0.56	0.014	0.022	4		L1	3.32	3.82	0.131	0.150	2	
D	14.85	15.25	0.585	0.600	3		ØΡ	3.54	3.73	0.139	0.147		
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118		

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}$ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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